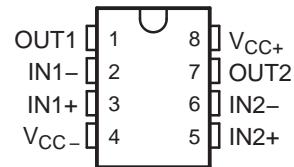


FEATURES

- Dual-Supply Operation . . . ± 5 V to ± 18 V
- Low Noise Voltage . . . 4.5 nV/ $\sqrt{\text{Hz}}$
- Low Input Offset Voltage . . . 0.15 mV
- Low Total Harmonic Distortion . . . 0.002%
- High Slew Rate . . . 7 V/ μs
- High-Gain Bandwidth Product . . . 16 MHz
- High Open-Loop AC Gain . . . 800 at 20 kHz
- Large Output-Voltage Swing . . . 14.1 V to -14.6 V
- Excellent Gain and Phase Margins

D (SOIC), DGK (MSOP), OR P (PDIP) PACKAGE
(TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

The MC33078 is a bipolar dual operational amplifier with high-performance specifications for use in quality audio and data-signal applications. This device operates over a wide range of single- and dual-supply voltages and offers low noise, high-gain bandwidth, and high slew rate. Additional features include low total harmonic distortion, excellent phase and gain margins, large output voltage swing with no deadband crossover distortion, and symmetrical sink/source performance.

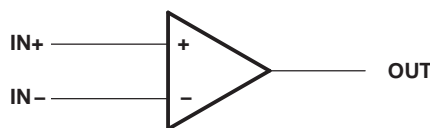
ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾
-40°C to 85°C	PDIP – P	Tube of 50	MC33078P	MC33078P
	SOIC – D	Tube of 75	MC33078D	M33078
		Reel of 2500	MC33078DR	
		VSSOP/MSOP – DGK	Reel of 2500	MC33078DGKR
	Reel of 250		MC33078DGKT	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DGK: The actual top-side marking has one additional character that designates the assembly/test site.

SYMBOL (EACH AMPLIFIER)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

MC33078
DUAL HIGH-SPEED LOW-NOISE OPERATIONAL AMPLIFIER

SLLS633C – OCTOBER 2004 – REVISED NOVEMBER 2006

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC+}	Supply voltage ⁽²⁾		18	V
V _{CC-}	Supply voltage ⁽²⁾		-18	V
V _{CC+} – V _{CC-}	Supply voltage		36	V
	Input voltage, either input ⁽²⁾⁽³⁾		V _{CC+} or V _{CC-}	V
	Input current ⁽⁴⁾		±10	mA
	Duration of output short circuit ⁽⁵⁾		Unlimited	
θ _{JA}	Package thermal impedance, junction to free air ⁽⁶⁾⁽⁷⁾	D package	97	°C/W
		DGK package	172	
		P package	85	
T _J	Operating virtual junction temperature		150	°C
T _{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
- (3) The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
- (4) Excessive input current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless some limiting resistance is used.
- (5) The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.
- (6) Maximum power dissipation is a function of T_{J(max)}, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_{J(max)} – T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

		MIN	MAX	UNIT
V _{CC-}	Supply voltage	-5	-18	V
V _{CC+}		5	18	
T _A	Operating free-air temperature range	-40	85	°C

Electrical Characteristics

$V_{CC-} = -15\text{ V}$, $V_{CC+} = 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
V_{IO}	Input offset voltage	$V_O = 0$, $R_S = 10\ \Omega$, $V_{CM} = 0$	$T_A = 25^\circ\text{C}$	0.15	2	3	mV	
			$T_A = -40^\circ\text{C}$ to 85°C					
αV_{IO}	Input offset voltage temperature coefficient	$V_O = 0$, $R_S = 10\ \Omega$, $V_{CM} = 0$	$T_A = -40^\circ\text{C}$ to 85°C		2		$\mu\text{V}/^\circ\text{C}$	
I_{IB}	Input bias current	$V_O = 0$, $V_{CM} = 0$	$T_A = 25^\circ\text{C}$	300	750	800	nA	
			$T_A = -40^\circ\text{C}$ to 85°C					
I_{IO}	Input offset current	$V_O = 0$, $V_{CM} = 0$	$T_A = 25^\circ\text{C}$	25	150	175	nA	
			$T_A = -40^\circ\text{C}$ to 85°C					
V_{ICR}	Common-mode input voltage range	$\Delta V_{IO} = 5\text{ mV}$, $V_O = 0$		± 13	± 14		V	
A_{VD}	Large-signal differential voltage amplification	$R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{ V}$	$T_A = 25^\circ\text{C}$	90	110	85	dB	
			$T_A = -40^\circ\text{C}$ to 85°C					
V_{OM}	Maximum output voltage swing	$V_{ID} = \pm 1\text{ V}$	$R_L = 600\ \Omega$	V_{OM+}	10.7		V	
				V_{OM-}	-11.9			
			$R_L = 2\text{ k}\Omega$	V_{OM+}	13.2	13.8		
				V_{OM-}	-13.2	-13.7		
			$R_L = 10\text{ k}\Omega$	V_{OM+}	13.5	14.1		
				V_{OM-}	-14	-14.6		
CMMR	Common-mode rejection ratio	$V_{IN} = \pm 13\text{ V}$		80	100		dB	
$k_{SVR}^{(1)}$	Supply-voltage rejection ratio	$V_{CC+} = 5\text{ V}$ to 15 V , $V_{CC-} = -5\text{ V}$ to -15 V		80	105		dB	
I_{OS}	Output short-circuit current	$ V_{ID} = 1\text{ V}$, Output to GND	Source current	15	29	-20	-37	mA
			Sink current					
I_{CC}	Supply current (per channel)	$V_O = 0$	$T_A = 25^\circ\text{C}$	2.05	2.5	2.75	mA	
			$T_A = -40^\circ\text{C}$ to 85°C					

(1) Measured with $V_{CC\pm}$ differentially varied at the same time

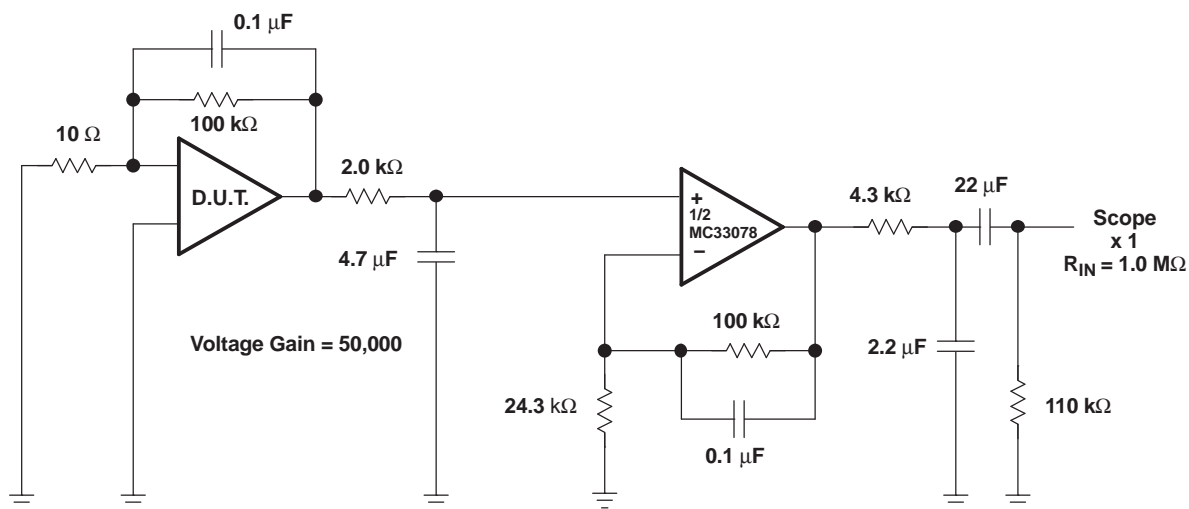
Operating Characteristics

$V_{CC-} = -15\text{ V}$, $V_{CC+} = 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$A_{VD} = 1$, $V_{IN} = -10\text{ V}$ to 10 V , $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		5	7		$\text{V}/\mu\text{s}$
GBW	Gain bandwidth product	$f = 100\text{ kHz}$		10	16		MHz
B_1	Unity gain frequency	Open loop			9		MHz
G_m	Gain margin	$R_L = 2\text{ k}\Omega$	$C_L = 0\text{ pF}$		-11		dB
			$C_L = 100\text{ pF}$		-6		
Φ_m	Phase margin	$R_L = 2\text{ k}\Omega$	$C_L = 0\text{ pF}$		55		deg
			$C_L = 100\text{ pF}$		40		
Amp-to-amp isolation		$f = 20\text{ Hz}$ to 20 kHz			-120		dB
Power bandwidth		$V_O = 27\text{ V}_{(PP)}$, $R_L = 2\text{ k}\Omega$, $\text{THD} \leq 1\%$			120		kHz
THD	Total harmonic distortion	$V_O = 3\text{ V}_{\text{rms}}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega$, $f = 20\text{ Hz}$ to 20 kHz			0.002		%
Z_o	Open-loop output impedance	$V_O = 0$, $f = 9\text{ MHz}$			37		Ω
r_{id}	Differential input resistance	$V_{CM} = 0$			175		$\text{k}\Omega$
C_{id}	Differential input capacitance	$V_{CM} = 0$			12		pF
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 100\ \Omega$			4.5		$\text{nV}/\sqrt{\text{Hz}}$
I_n	Equivalent input noise current	$f = 1\text{ kHz}$			0.5		$\text{pA}/\sqrt{\text{Hz}}$

MC33078
DUAL HIGH-SPEED LOW-NOISE OPERATIONAL AMPLIFIER

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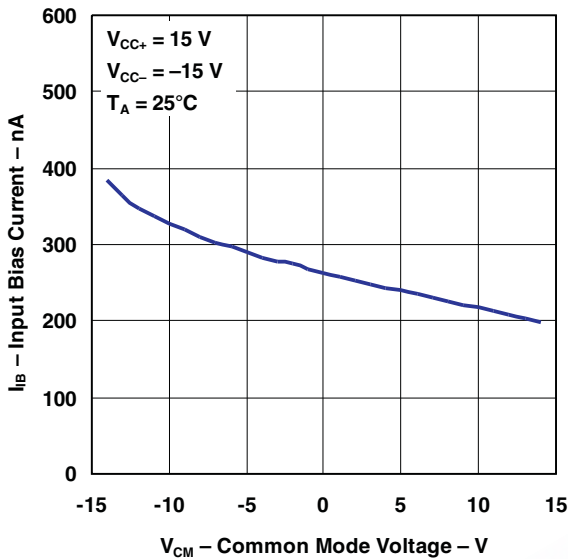
NOTE: All capacitors are non-polarized.

Figure 1. Voltage Noise Test Circuit (0.1 Hz to 10 Hz)

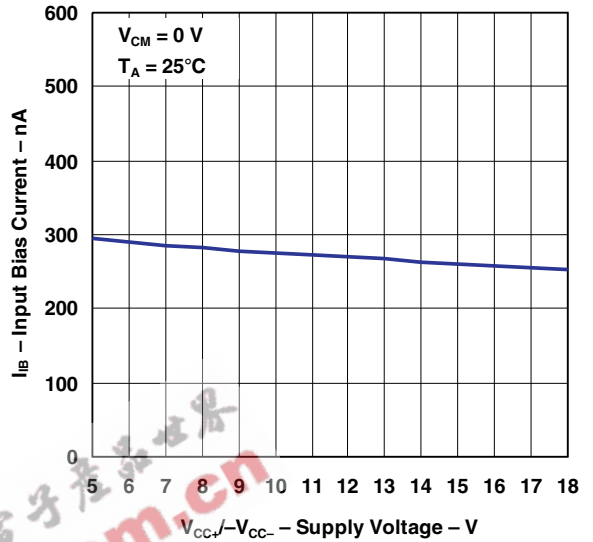
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TYPICAL CHARACTERISTICS

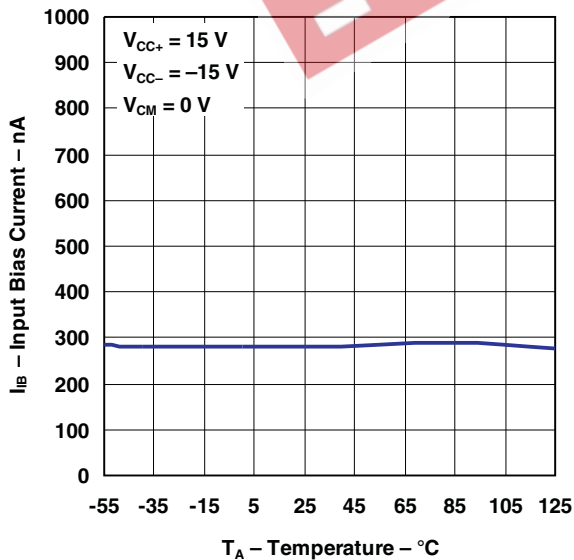
INPUT BIAS CURRENT
 VS
COMMON-MODE VOLTAGE



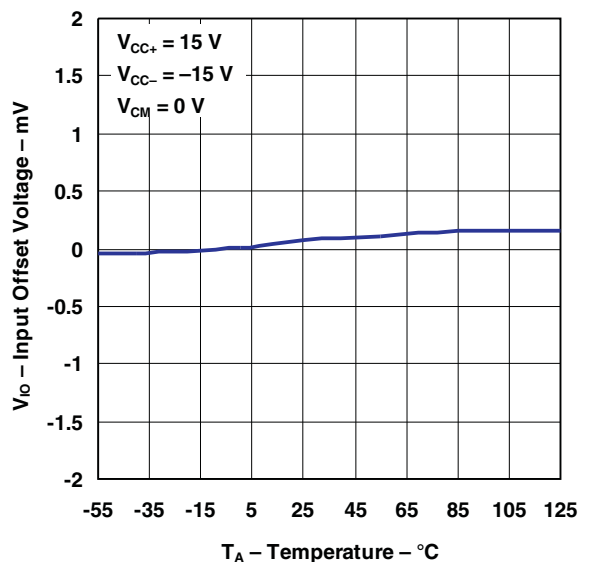
INPUT BIAS CURRENT
 VS
SUPPLY VOLTAGE



INPUT BIAS CURRENT
 VS
TEMPERATURE

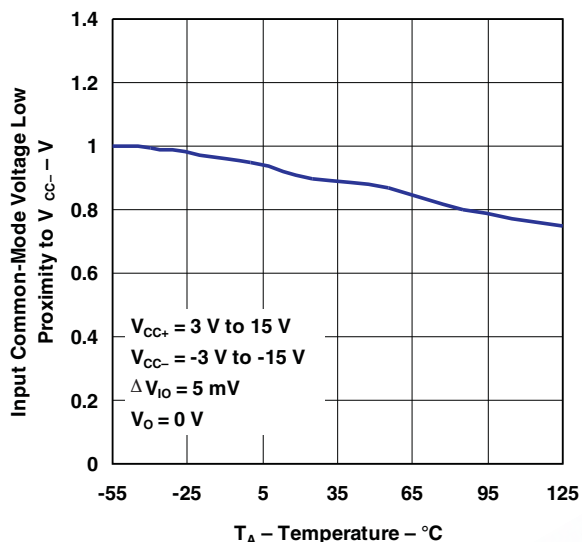


INPUT OFFSET VOLTAGE
 VS
TEMPERATURE

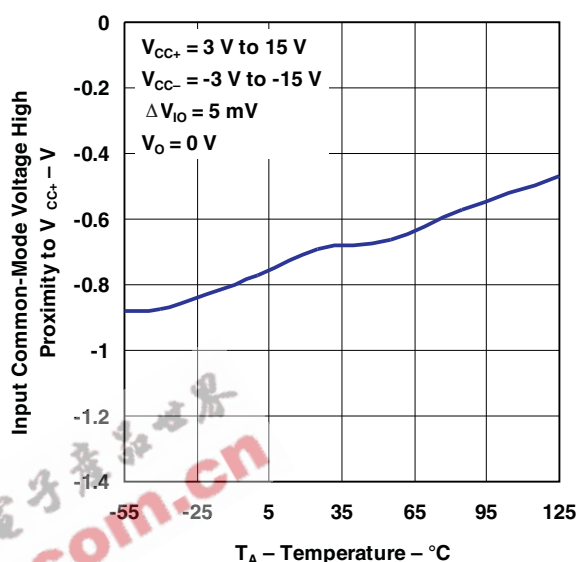


TYPICAL CHARACTERISTICS (continued)

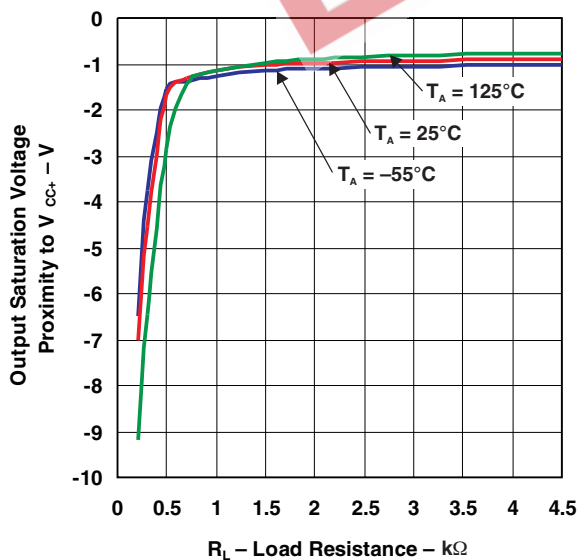
INPUT COMMON-MODE VOLTAGE
 LOW PROXIMITY TO V_{CC-}
 VS
 TEMPERATURE



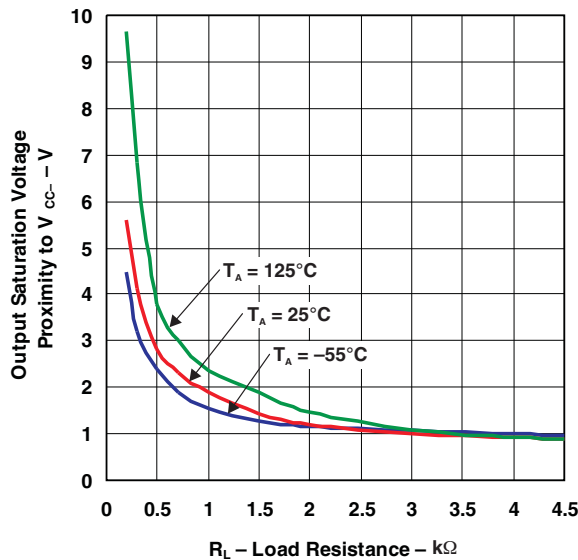
INPUT COMMON-MODE VOLTAGE
 HIGH PROXIMITY TO V_{CC+}
 VS
 TEMPERATURE



OUTPUT SATURATION VOLTAGE PROXIMITY TO V_{CC+}
 VS
 LOAD RESISTANCE

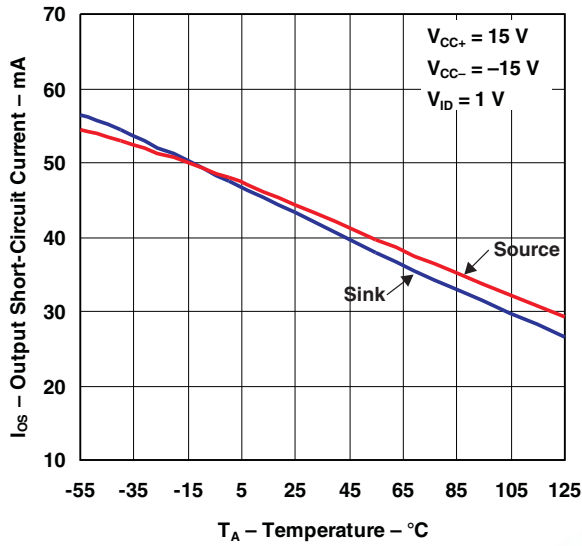


OUTPUT SATURATION VOLTAGE PROXIMITY TO V_{CC-}
 VS
 LOAD RESISTANCE

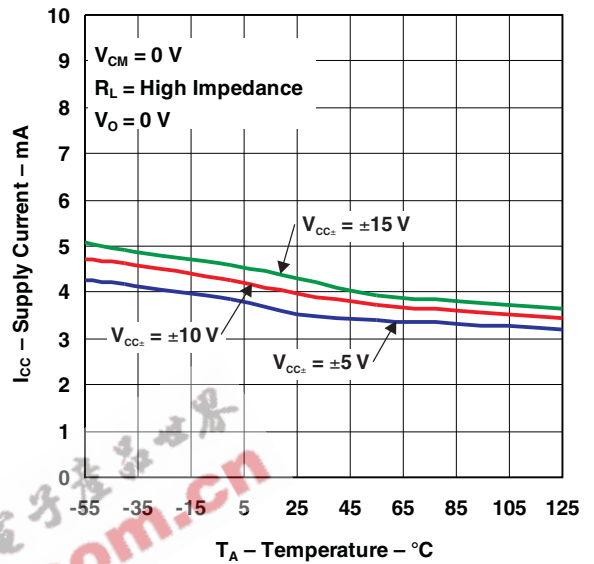


TYPICAL CHARACTERISTICS (continued)

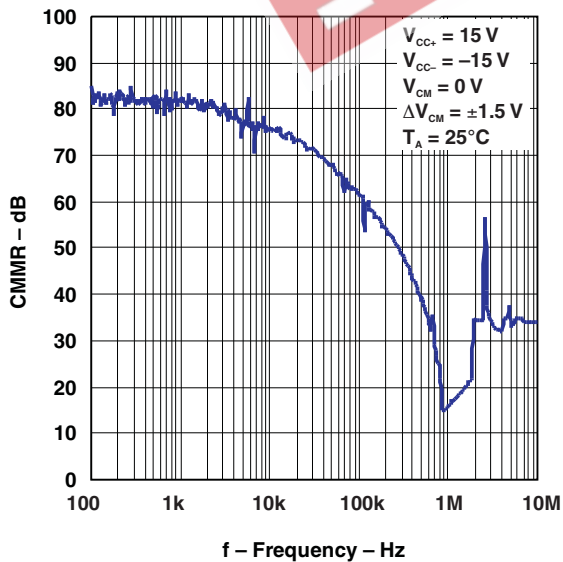
**OUTPUT SHORT-CIRCUIT CURRENT
VS
TEMPERATURE**



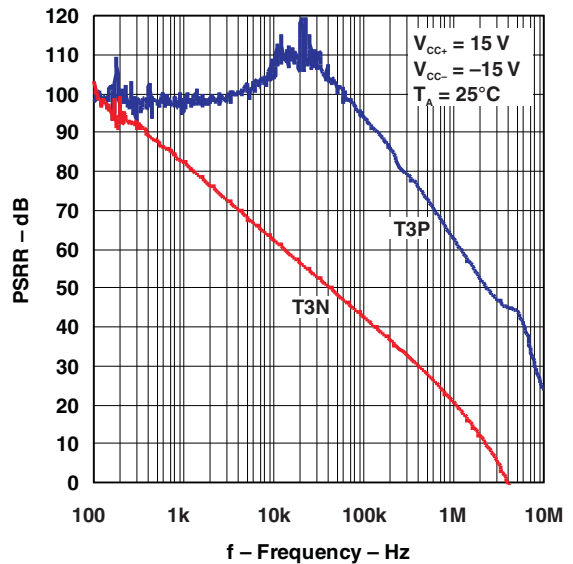
**SUPPLY CURRENT
VS
TEMPERATURE**



**CMRR
VS
FREQUENCY**

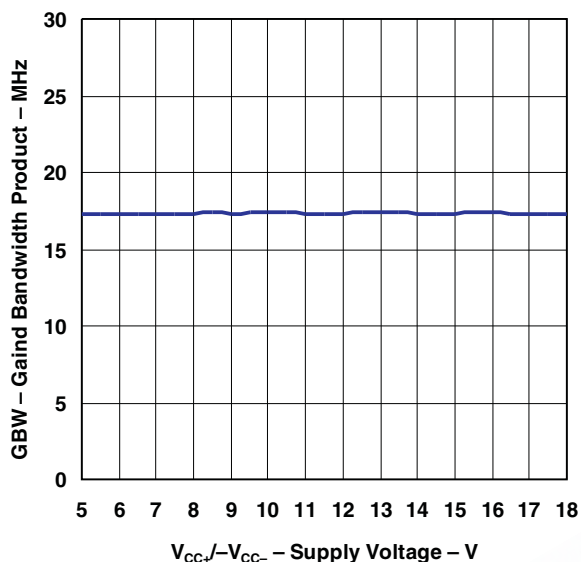


**PSSR
VS
FREQUENCY**

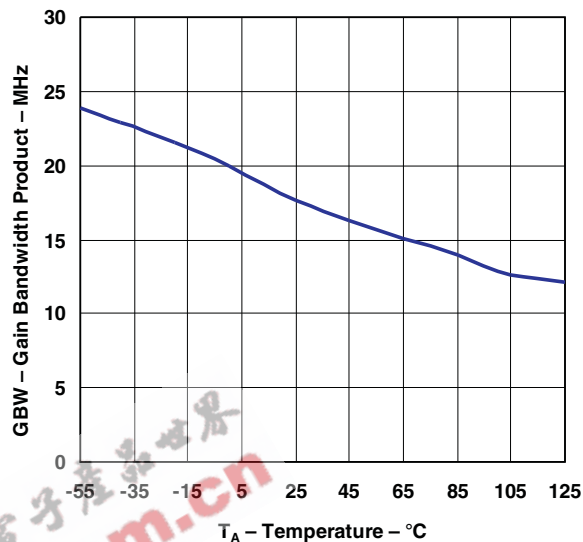


TYPICAL CHARACTERISTICS (continued)

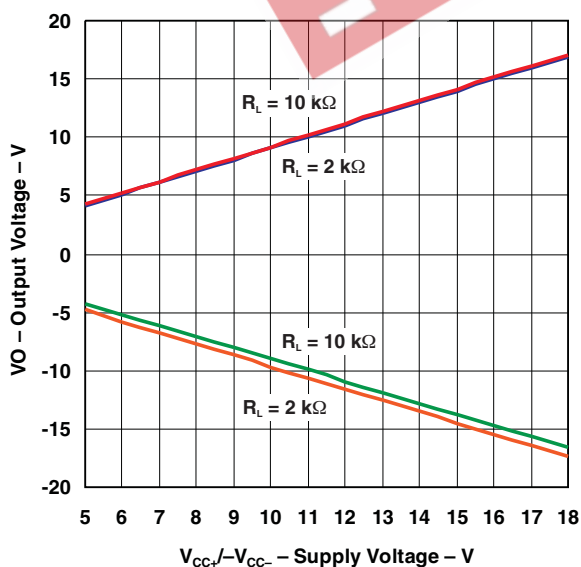
GAIN BANDWIDTH PRODUCT
 VS
 SUPPLY VOLTAGE



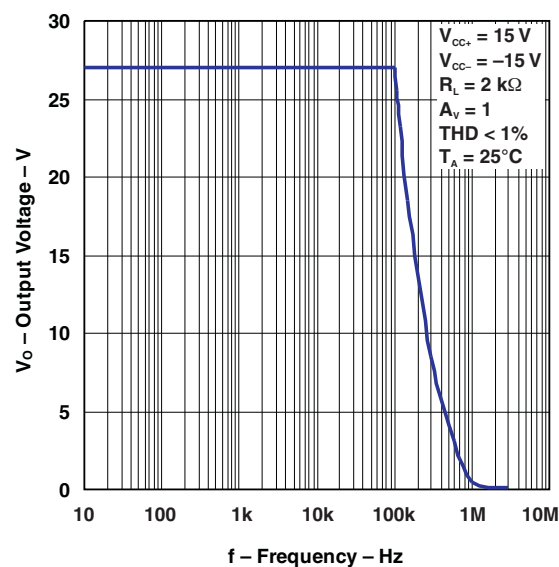
GAIN BANDWIDTH PRODUCT
 VS
 TEMPERATURE



OUTPUT VOLTAGE
 VS
 SUPPLY VOLTAGE

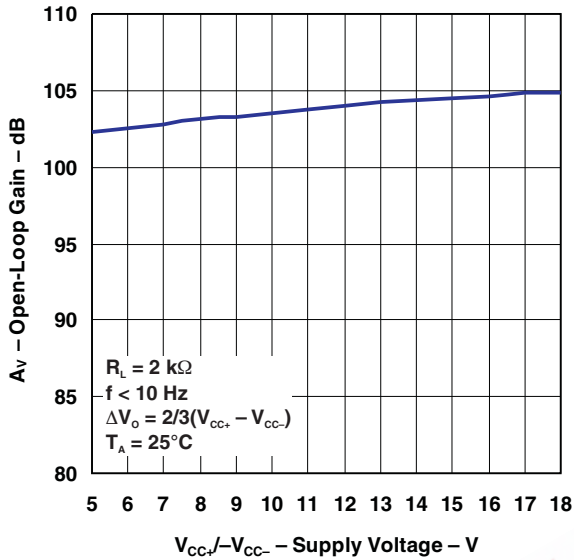


OUTPUT VOLTAGE
 VS
 FREQUENCY

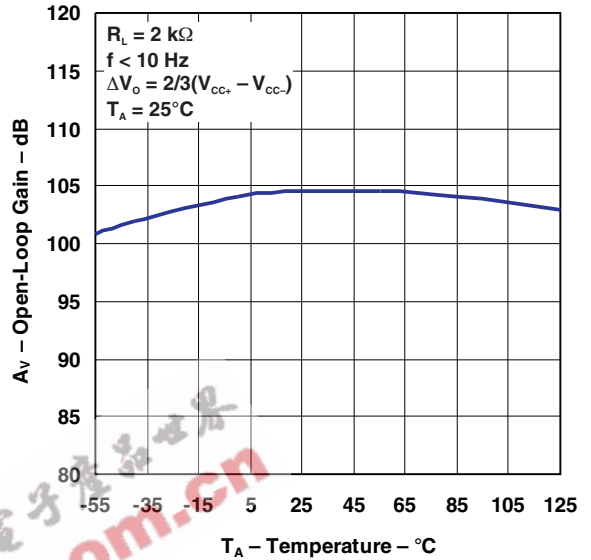


TYPICAL CHARACTERISTICS (continued)

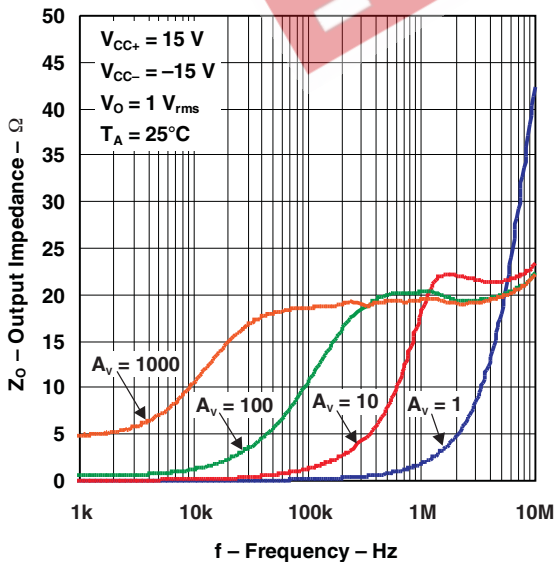
OPEN-LOOP GAIN
vs
SUPPLY VOLTAGE



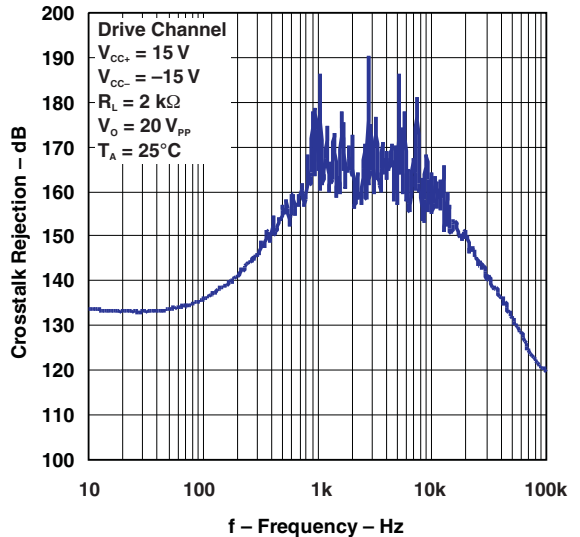
OPEN-LOOP GAIN
vs
TEMPERATURE



OUTPUT IMPEDANCE
vs
FREQUENCY

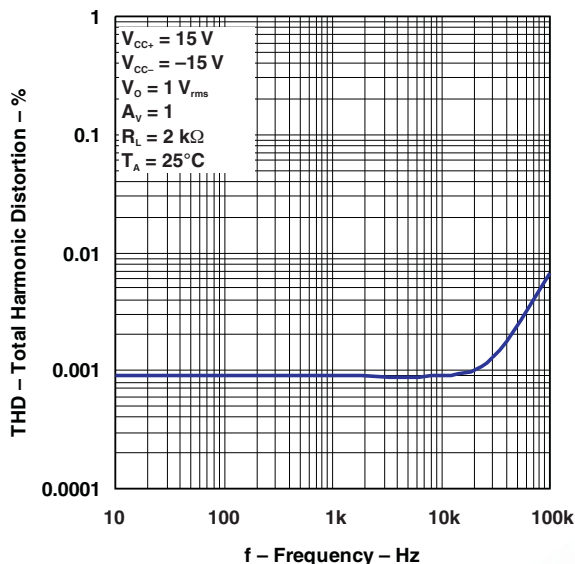


CROSSTALK REJECTION
vs
FREQUENCY

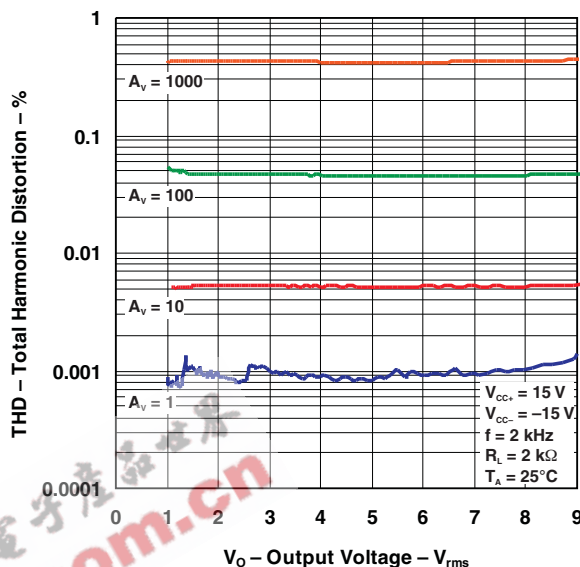


TYPICAL CHARACTERISTICS (continued)

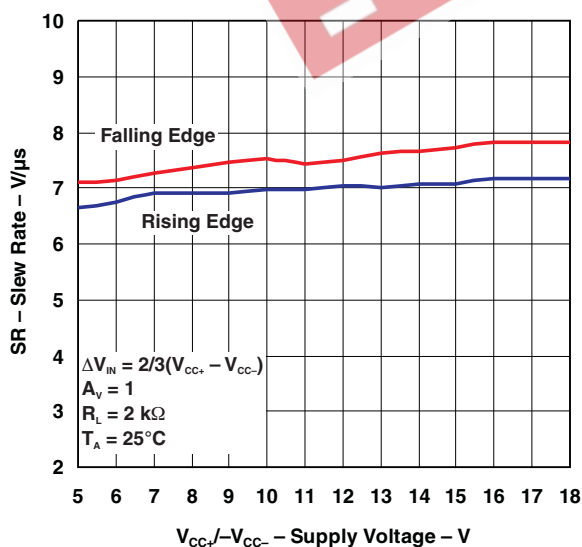
TOTAL HARMONIC DISTORTION
 VS
 FREQUENCY



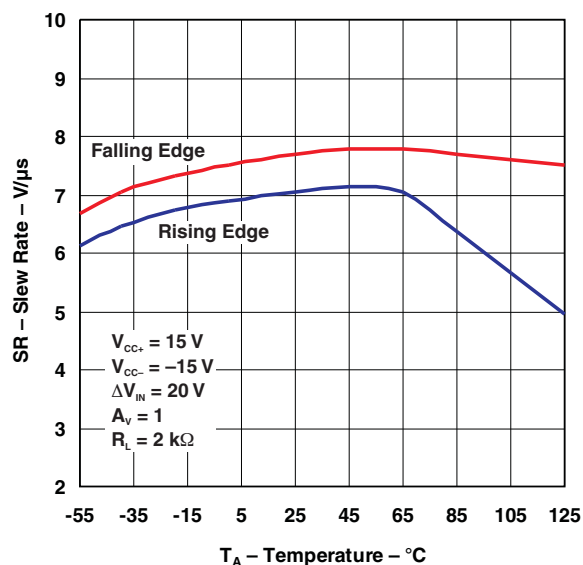
TOTAL HARMONIC DISTORTION
 VS
 OUTPUT VOLTAGE



SLEW RATE
 VS
 SUPPLY VOLTAGE

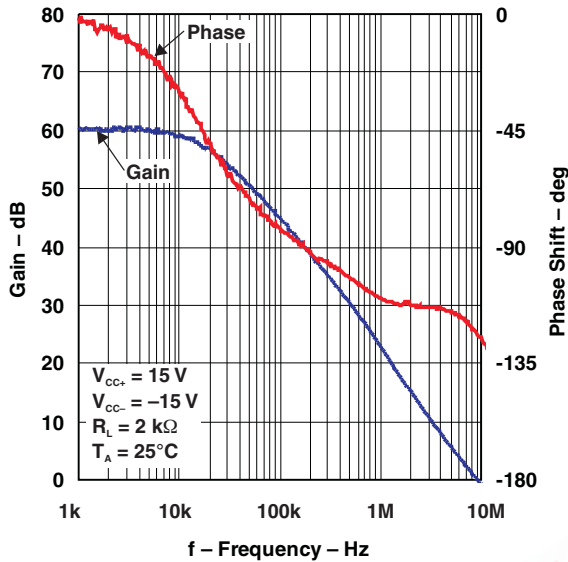


SLEW RATE
 VS
 TEMPERATURE

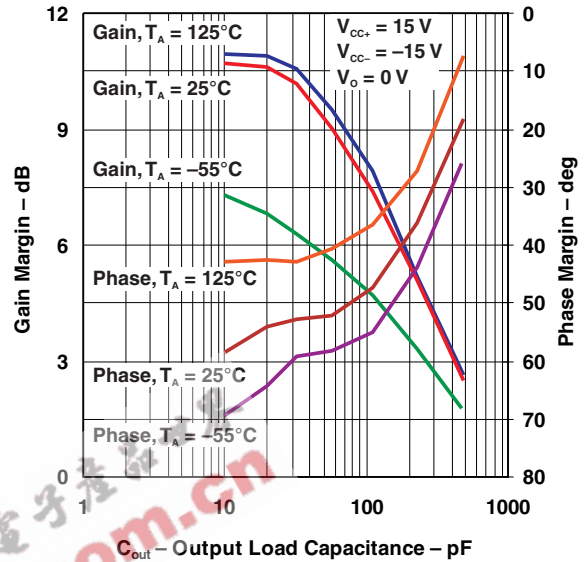


TYPICAL CHARACTERISTICS (continued)

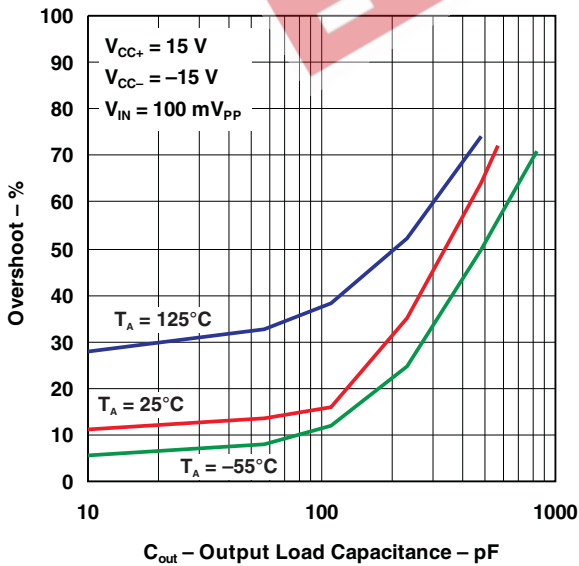
GAIN AND PHASE VS FREQUENCY



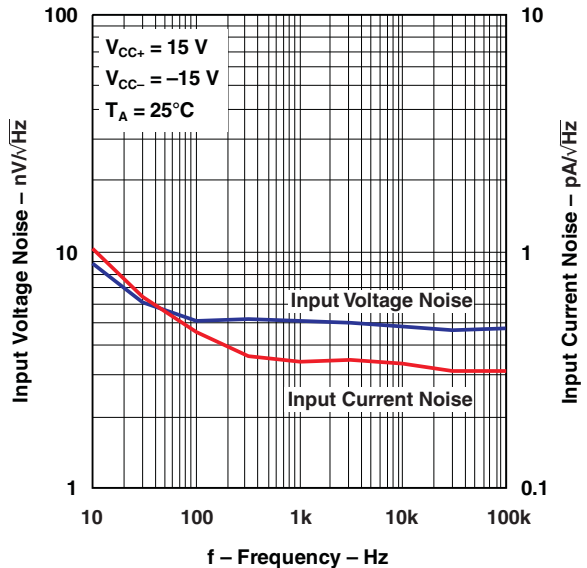
GAIN AND PHASE MARGIN VS OUTPUT LOAD CAPACITANCE



OVERSHOOT VS OUTPUT LOAD CAPACITANCE

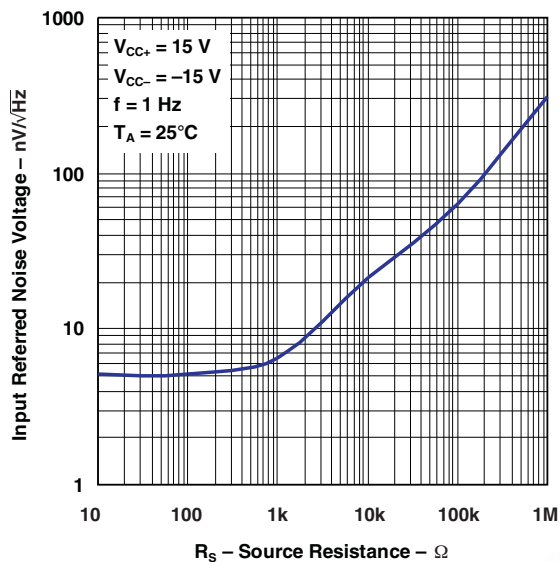


INPUT VOLTAGE AND CURRENT NOISE VS FREQUENCY

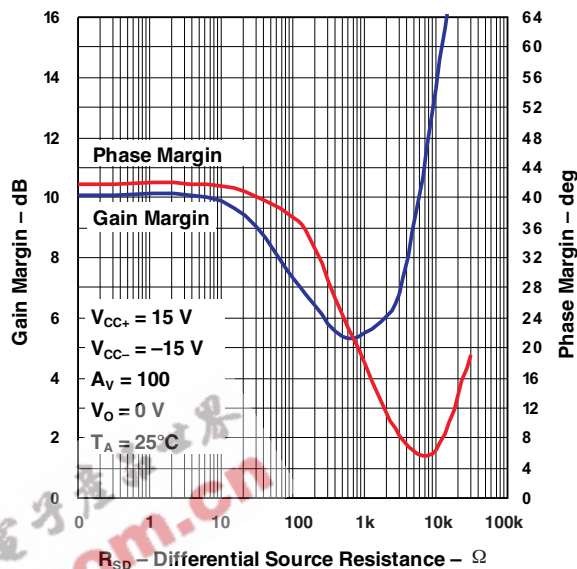


TYPICAL CHARACTERISTICS (continued)

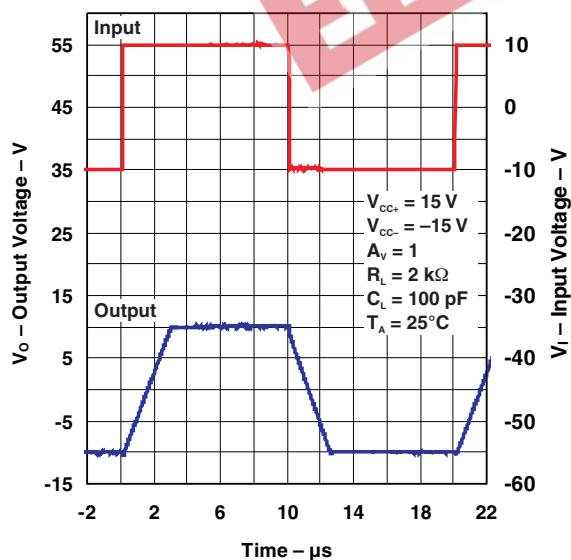
INPUT REFERRED NOISE VOLTAGE
 VS
 SOURCE RESISTANCE



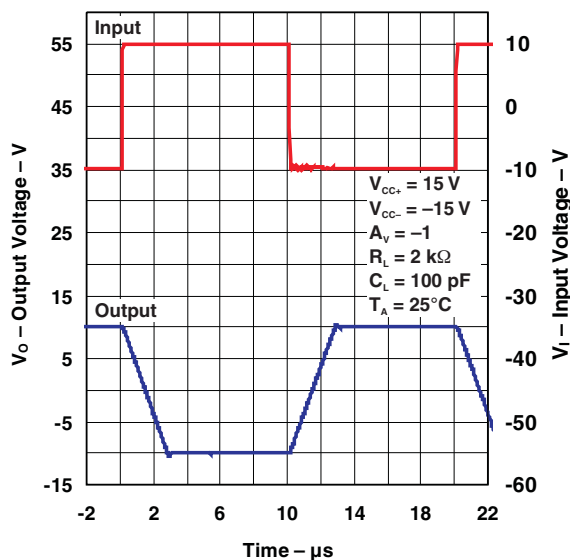
GAIN AND PHASE MARGIN
 VS
 DIFFERENTIAL SOURCE RESISTANCE



LARGE SIGNAL TRANSIENT RESPONSE
 (AV = 1)

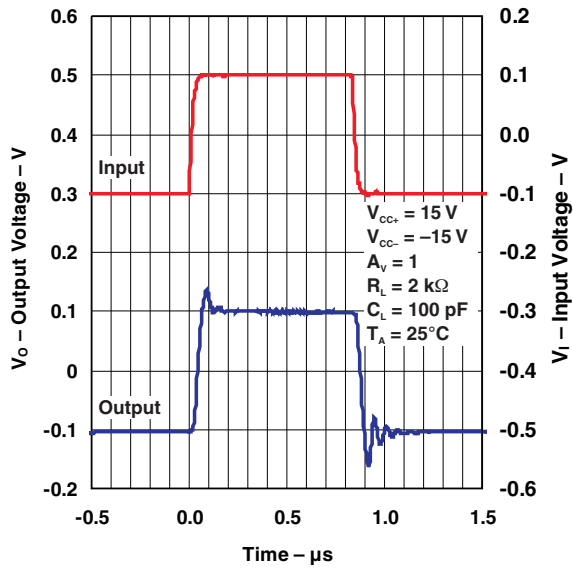


LARGE SIGNAL TRANSIENT RESPONSE
 (AV = -1)

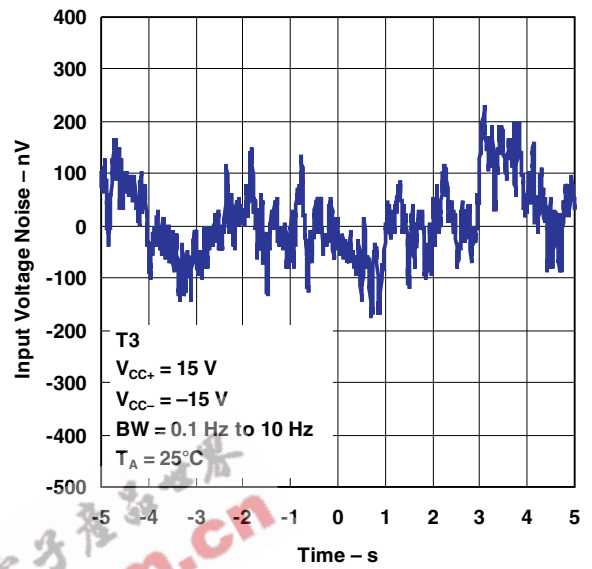


TYPICAL CHARACTERISTICS (continued)

SMALL SIGNAL TRANSIENT RESPONSE



LOW_FREQUENCY NOISE



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APPLICATION INFORMATION

Output Characteristics

All operating characteristics are specified with 100-pF load capacitance. The MC33078 can drive higher capacitance loads. However, as the load capacitance increases, the resulting response pole occurs at lower frequencies, causing ringing, peaking, or oscillation. The value of the load capacitance at which oscillation occurs varies from lot to lot. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem (see Figure 2).

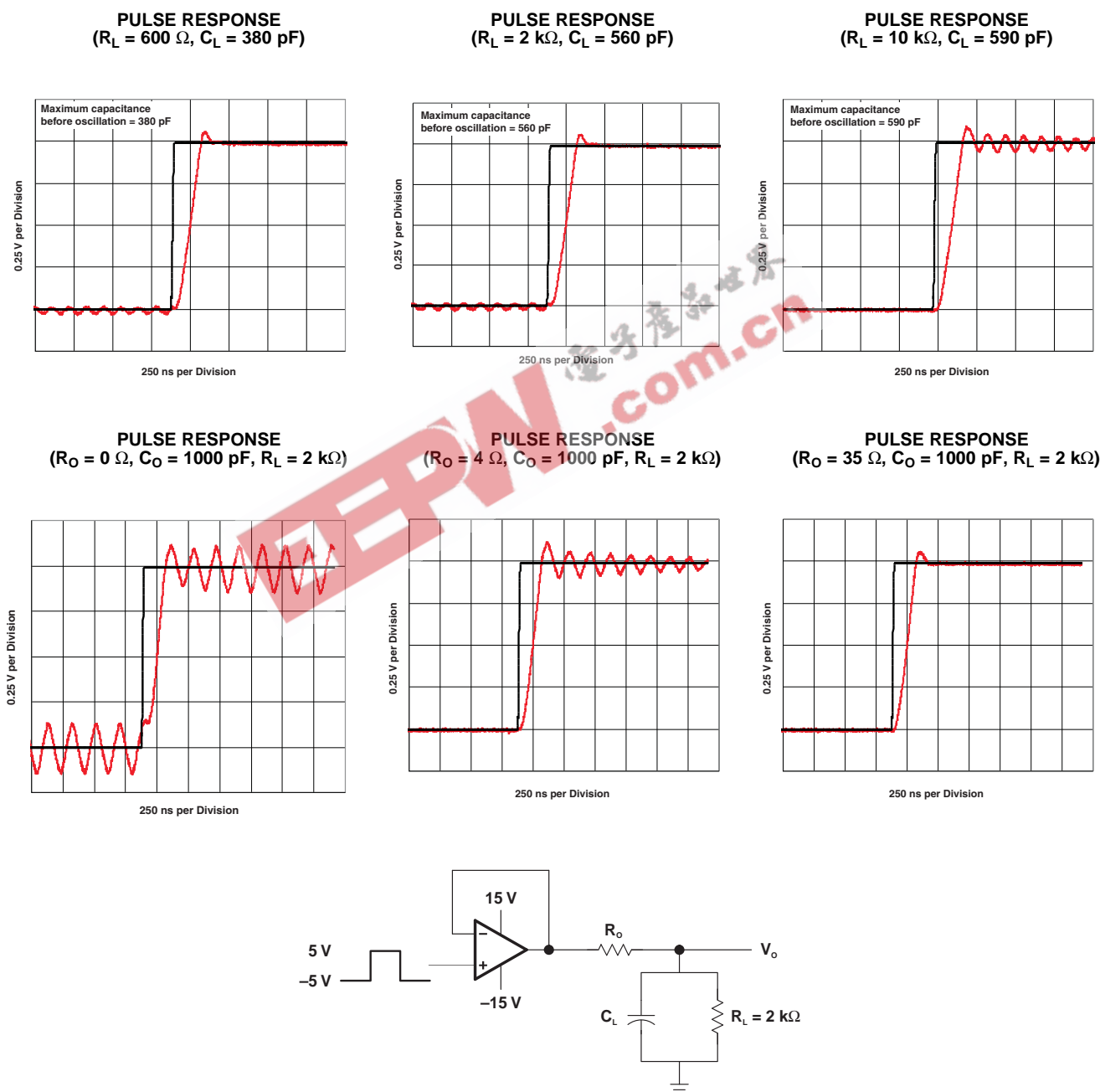


Figure 2. Output Characteristics

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MC33078D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKRG4	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKT	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKTG4	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
MC33078PE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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MECHANICAL DATA

MPDI001A – JANUARY 1995 – REVISED JUNE 1999

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

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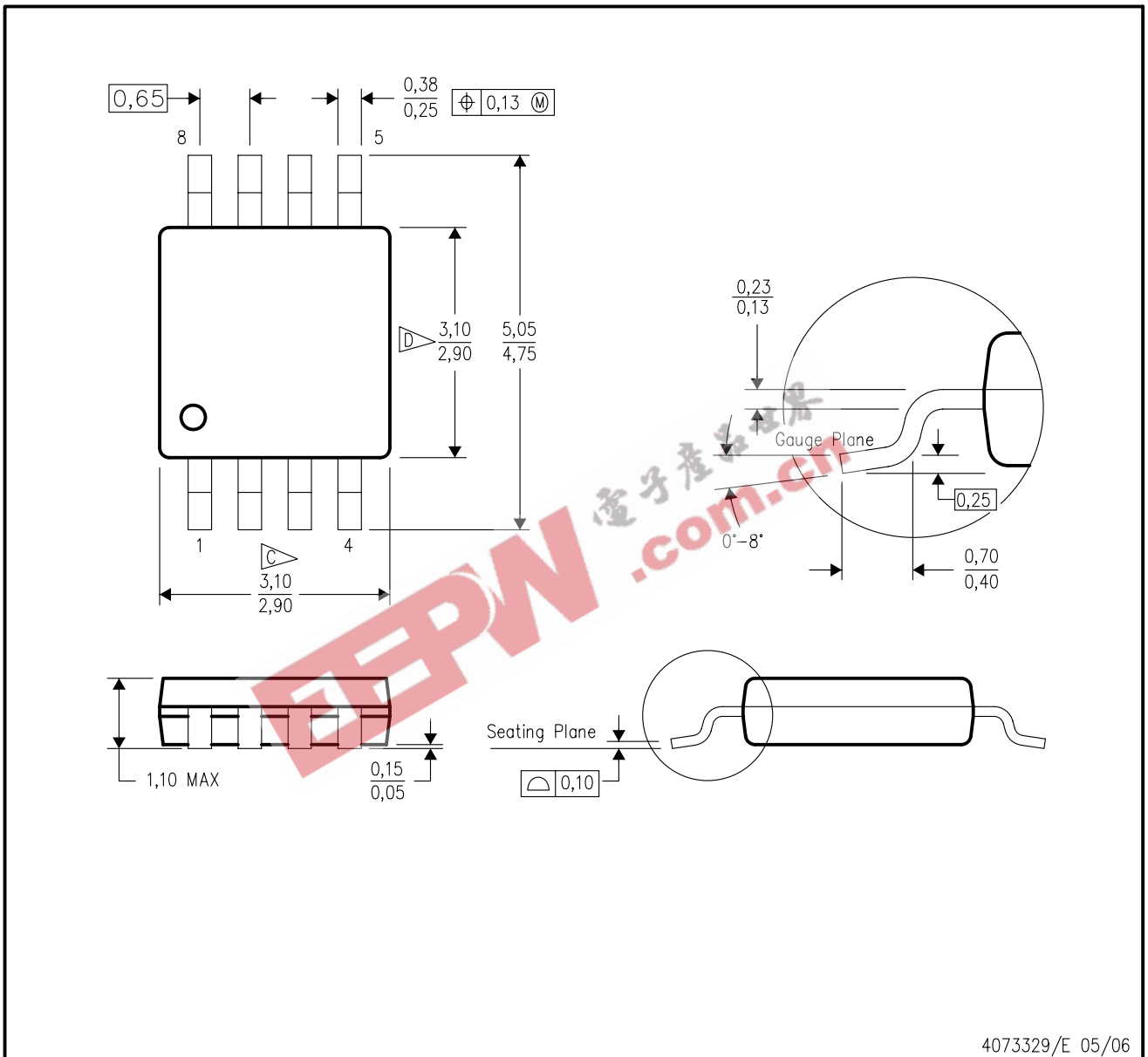


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MECHANICAL DATA

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

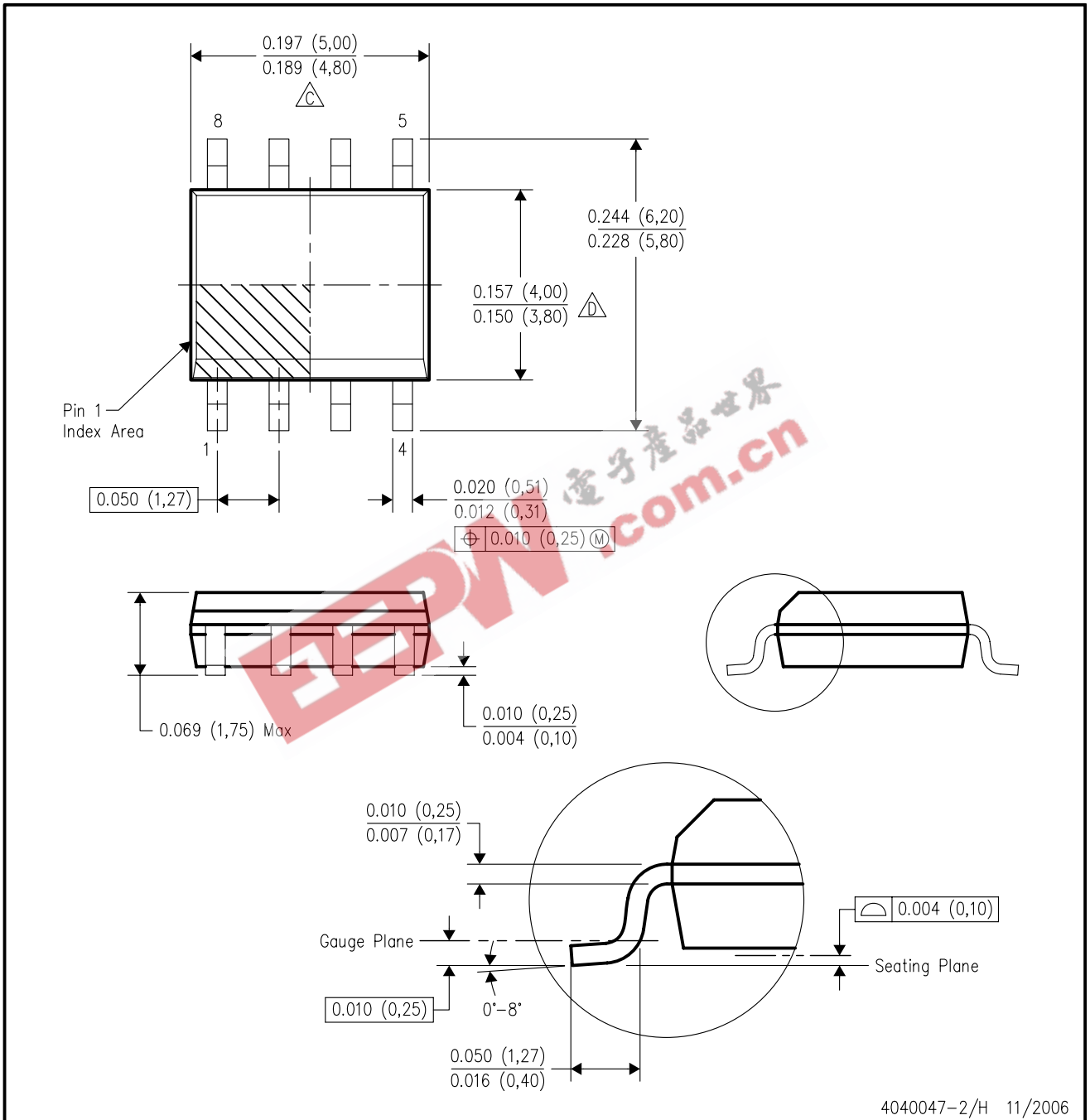


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
 - E. Falls within JEDEC MO-187 variation AA, except interlead flash.

MECHANICAL DATA

D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



4040047-2/H 11/2006

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - △C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
 - △D Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
 - Reference JEDEC MS-012 variation AA.

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